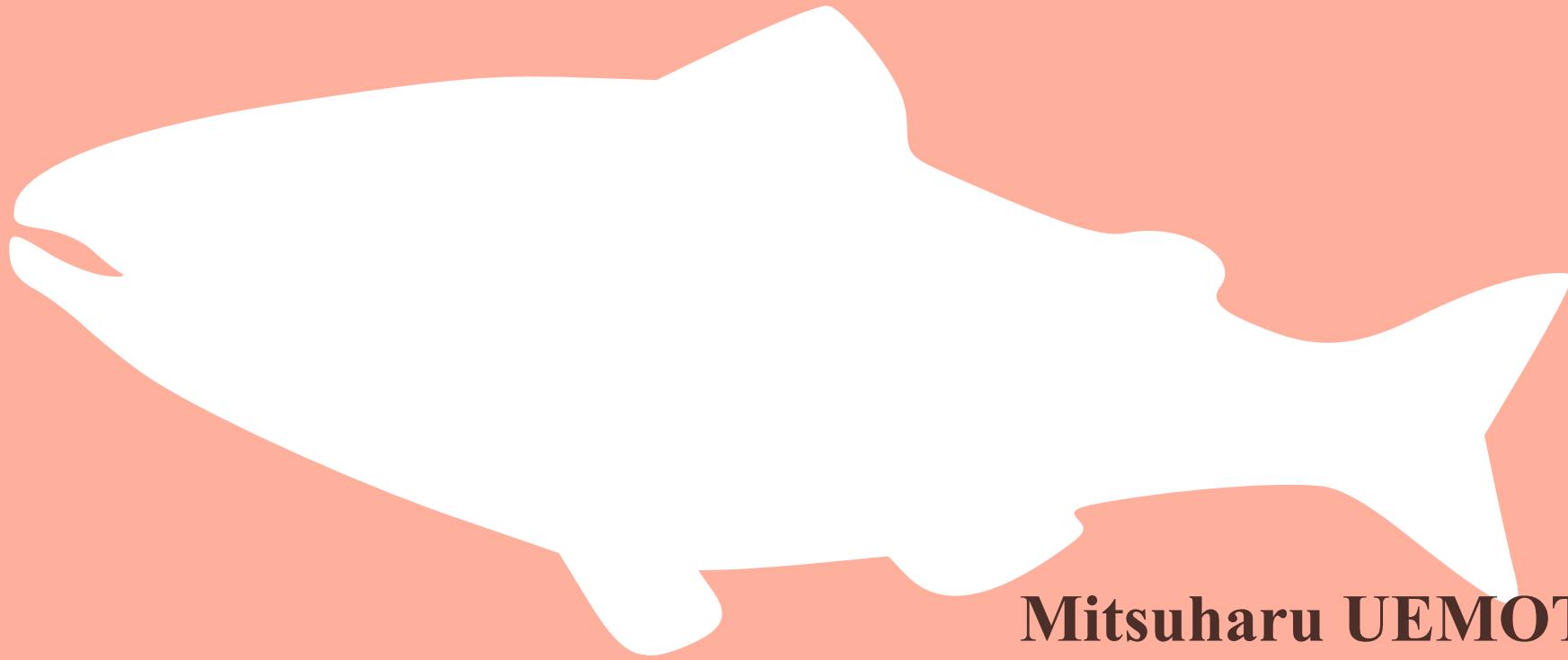


How to Use SALMON-2: Periodic Systems

Overview



Mitsuharu UEMOTO

Center for Computational Sciences, University of Tsukuba

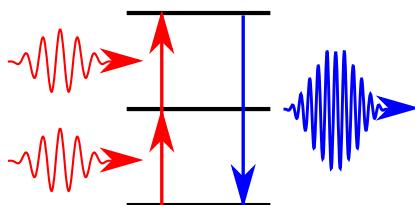
Introduction of RT-TDDFT for Solid

Real-Time TDDFT for “Nonlinear Optics” in Solid

- First-principle TDDFT-based electron dynamics simulation
- Light-matter interaction between “**strong laser pulse**” and “**solid crystal**”

Real-Time Calculation

- Linear response
 - Dielectric Function
- Nonlinear response:
 - SHG, THG, Kerr effects

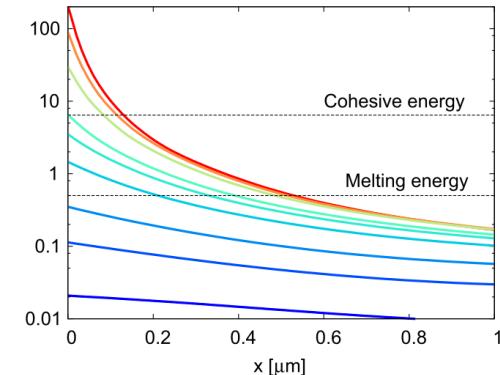
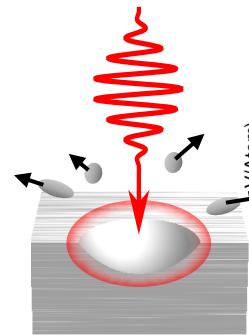


$$\mathbf{P} = \chi^{(1)} \mathbf{E} + \chi^{(2)} \mathbf{E}^2 + \chi^{(3)} \mathbf{E}^3 + \dots$$

- Light matter energy transfer

Multiscale calculation

- Light Propagation
 - Damaging / Ablation
 - Non-thermal laser processing

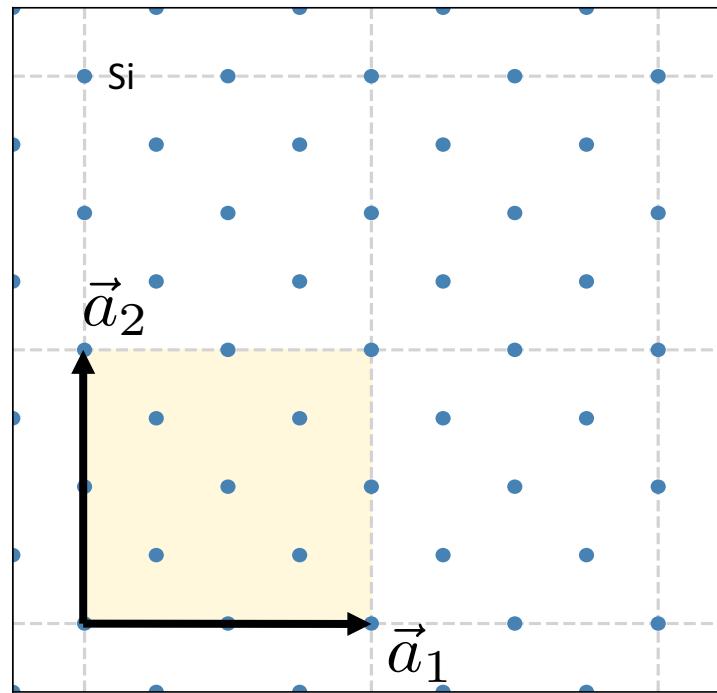
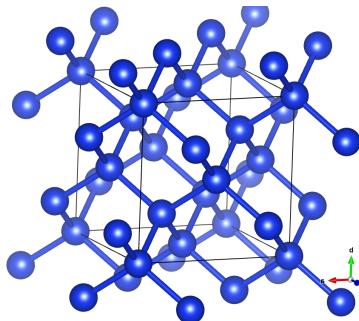


S.A. Sato, K. Yabana et al, PRB **92**, 1 (2015).

Solid Crystal



Silicon (Wikipedia.org)



- **Solid Crystal**
 - Periodic structure of atoms
 - Result is unmodified to the shift by the lattice vector:

$$\mathbf{R} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3$$

Periodic Condition and Bloch Wavefunction

$$[\mathcal{T}_{\mathbf{R}}, \mathcal{H}] = 0$$

- Hamiltonian is invariant to the shift by \mathbf{R}

$$V(\mathbf{r} + \mathbf{R}) = V(\mathbf{r}) \rightarrow \hat{T}_{\mathbf{R}} \text{ Translation Operator}$$

Hamiltonian and Translation operator has common eigenstate:

$$\mathcal{H}\psi = \epsilon\psi \quad \mathcal{T}_{\mathbf{R}}\psi = \lambda\psi$$

Bloch's theorem

The electron's wavefunction in periodic system satisfy:

$$\psi_{b,\mathbf{k}}(\mathbf{r} + \mathbf{R}) = e^{i\mathbf{k}\mathbf{R}}\psi_{b,\mathbf{k}}(\mathbf{r}) \quad \begin{array}{l} \mathbf{k}: \text{Bloch wavevector} \\ \mathbf{b}: \text{Band Index} \end{array}$$

The Bloch wavefunction can rewritten by using the periodic function u_{bk} :

$$\psi_{b,\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\mathbf{r}}u_{b,\mathbf{k}}(\mathbf{r})$$

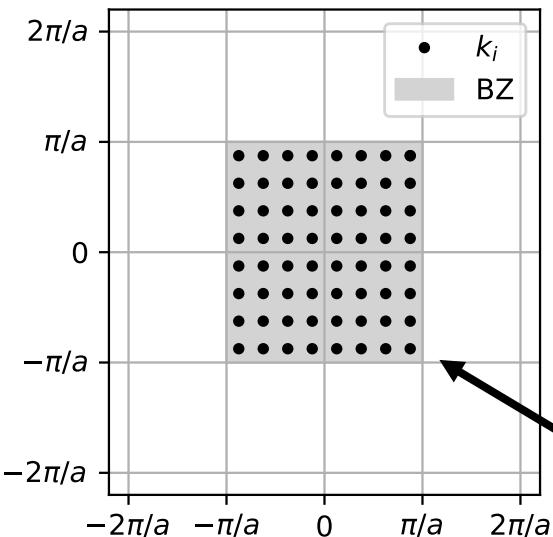
Brillouin Zone and K points

The \mathbf{k} values with arbitrary integer m corresponds to the same eigenstate

$$\mathbf{k}' = \mathbf{k} + \left(\frac{2\pi m_1}{a_1}, \frac{2\pi m_2}{a_2}, \frac{2\pi m_3}{a_3} \right) \quad u_{b,\mathbf{k}} e^{i\mathbf{k}\mathbf{R}} \leftrightarrow u_{b,\mathbf{k}'} e^{i\mathbf{k}'\mathbf{R}}$$

\mathbf{k} -vectors are restricted in the region of the reciprocal space

$$\left(-\frac{\pi}{a_1} \leq k_1 \leq \frac{\pi}{a_1} \right), \left(-\frac{\pi}{a_2} \leq k_2 \leq \frac{\pi}{a_2} \right), \left(-\frac{\pi}{a_3} \leq k_3 \leq \frac{\pi}{a_3} \right) \rightarrow \text{Brillouin Zone (BZ)}$$



Discretize BZ to finite number of \mathbf{k} -points:

$$u_{b,\mathbf{k}} \rightarrow u_{b,\mathbf{k}_i}$$

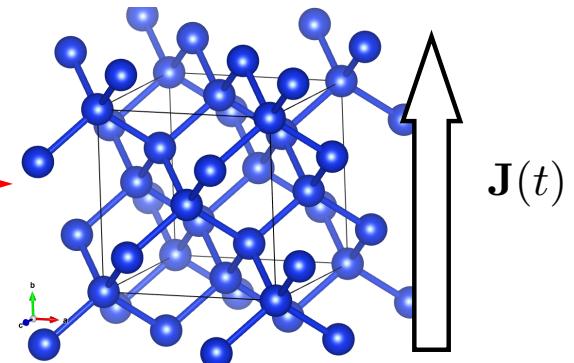
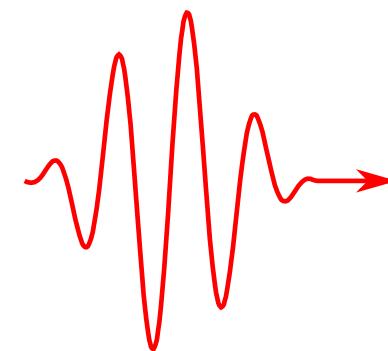
$$\iiint d\mathbf{k} f(\mathbf{k}) \rightarrow \sum_{\mathbf{k}_i} \omega(\mathbf{k}_i) f(\mathbf{k}_i)$$

Uniformly choose the k-points in the Brillouin Zone

Governing Equation in Periodic System

Incident Field

$$\mathbf{E}(t) = -\dot{\mathbf{A}}(t)/c$$



Time-Dependent Kohn-Sham (TDKS) equation in Periodic System:

$$i\hbar \frac{\partial}{\partial t} u_{b,\mathbf{k}}(\mathbf{r}, t) = \left[\frac{1}{2m} \left(-i\hbar\nabla + \hbar\mathbf{k} + \frac{e}{c}\mathbf{A}(t) \right)^2 + v_{\text{ion}} + v_{\text{H}} + v_{\text{XC}} \right] u_{b,\mathbf{k}}(\mathbf{r}, t)$$

KS orbit $u_{b,\mathbf{k}}$ Atomic potential v_{ion} Electron Interaction v_{H} v_{XC}

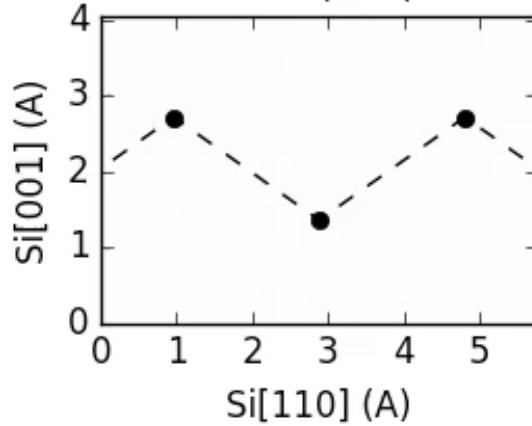
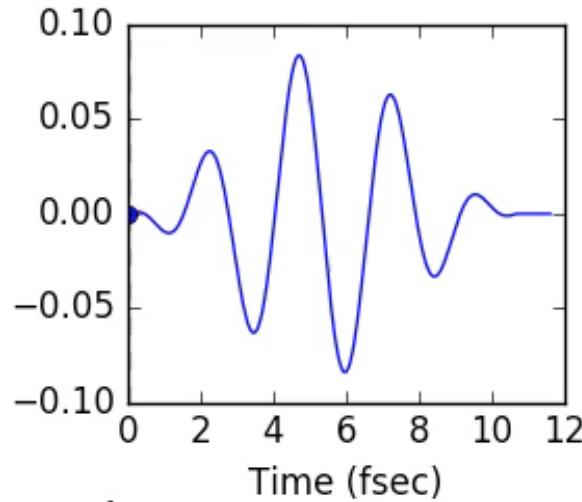
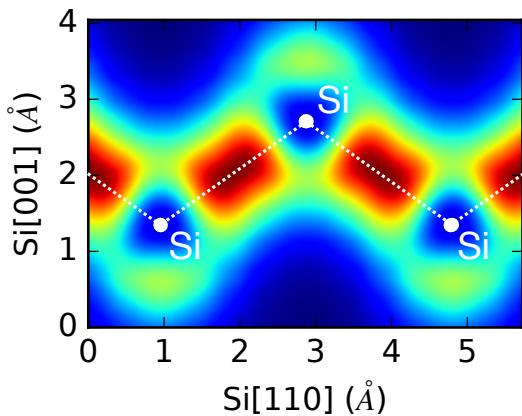
Compute TDKS equation by using Finite Difference Method on Real Space Grid

$$u_{b,\mathbf{k}}(\mathbf{r}) \rightarrow \text{zu(NL, NK, NB)}$$

Example of RT-TDDFT Calculation

$$\mathbf{A}(t) = \mathbf{A}_0 \cos^2 \frac{\pi t}{T} \sin \omega_1 t$$

- Frequency = 1.55 [eV]
- Intensity = 10^9 [W/cm²]
- Length = 10 [fs]



PART 1

Ground State Calculation

Ground State Calculation

Solve Kohn-Sham Equation

$$\varepsilon_{b,\mathbf{k}} u_{b,\mathbf{k}}(\mathbf{r}) = \left[\frac{1}{2m} (-\hbar\nabla + \hbar\mathbf{k})^2 + v_{\text{ion}} + v_{\text{H}} + v_{\text{XC}} \right] u_{b,\mathbf{k}}(\mathbf{r})$$

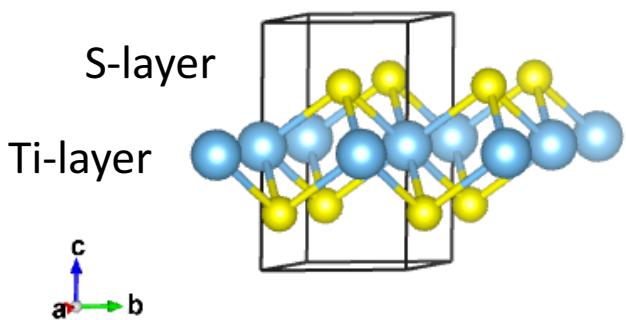
→ Initial State of the real-time calculation



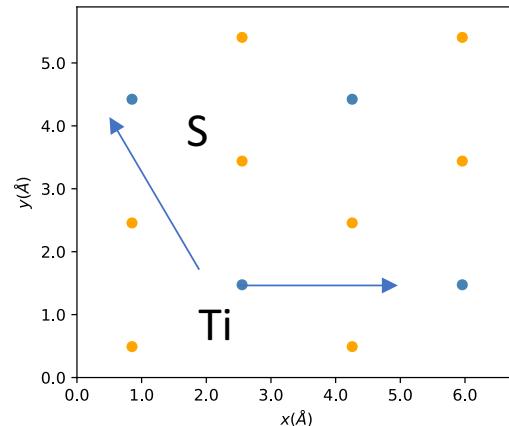
- Electron Single-particle Eigenenergy Spectra $\varepsilon_{b,\mathbf{k}}$
- Electron Density of States (DoS) $\rho(E) = \sum_{b,\mathbf{k}} \delta(E - \varepsilon_{b,\mathbf{k}}) f_{\mathbf{k}}$
- Charge Density Profile $n(\mathbf{r}) = \sum_{b,\mathbf{k}} |u_{b,\mathbf{k}}(\mathbf{r})|^2 f_{\mathbf{k}}$
- Total Energy E_{tot}

Example of Ground State Calculation

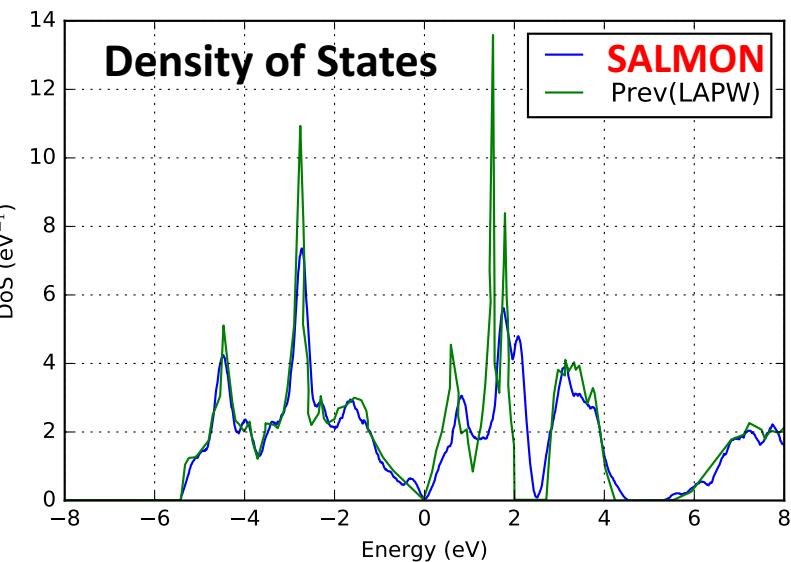
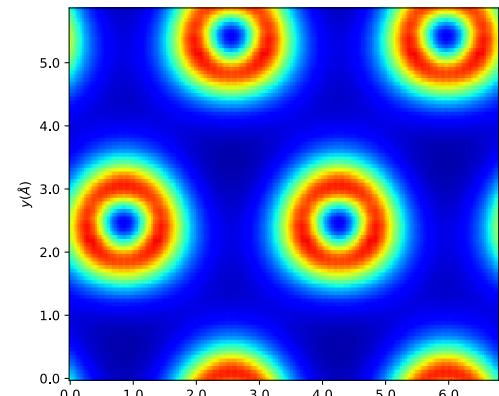
Crystal Structure



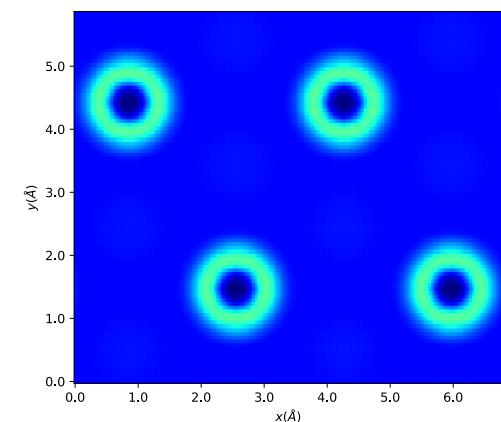
Top of View



S-layer



Ti-layer



PART 2

Linear Response Calculation (Dielectric Function)

Linear Response Calculation

Solve Time-dependent Kohn-Sham Equation

$$i\hbar \frac{\partial}{\partial t} u_{b,\mathbf{k}}(\mathbf{r}, t) = \left[\frac{1}{2m} \left(-i\hbar\nabla + \hbar\mathbf{k} + \frac{e}{c} \mathbf{A}(t) \right)^2 + v_{\text{ion}} + v_{\text{H}} + v_{\text{XC}} \right] u_{b,\mathbf{k}}(\mathbf{r}, t)$$

(with weak incident field: $\mathbf{A}(t)$, $\mathbf{E}(t)$)

$$\mathbf{A}(t) = \delta\mathbf{A} \theta(t)$$

$$\mathbf{E}(t) = -\delta\mathbf{E} \delta(t)$$



- Impulse response
- Dielectric Function
- Conductivity
- ...

$$J(t)$$

$$\epsilon_{ij}(\omega)$$

$$\sigma_{ij}(\omega)$$

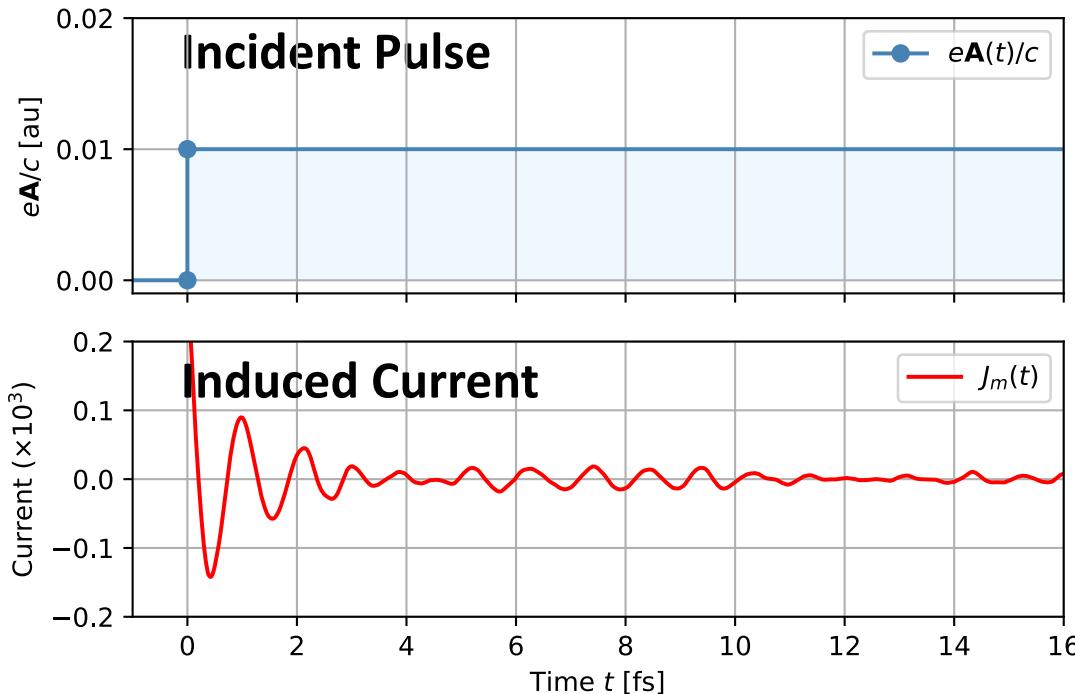
$$\mathbf{P}(\omega) = \frac{1}{4\pi} (\epsilon(\omega) - \mathbf{I}) \mathbf{E}(\omega)$$

$$\mathbf{J}(\omega) = \sigma(\omega) \mathbf{E}(\omega)$$

Linear Response (Dielectric Function)

Induced Current Density

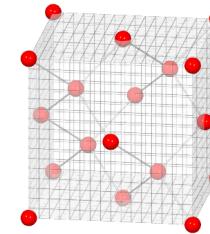
$$\mathbf{J}(t) = -\frac{e}{m} \sum_{b,\mathbf{k}} \frac{1}{\Omega} \int_{\Omega} \operatorname{Re} u_{b,\mathbf{k}}^*(\mathbf{r}, t) \left(-i\hbar\nabla + \hbar\mathbf{k} + \frac{e}{c} \mathbf{A}(t) \right)^2 u_{b,\mathbf{k}}(\mathbf{r}, t) \, d\mathbf{r} + \mathbf{J}_{\text{NL}}$$



Weak incident field

$$\mathbf{A}(t) = \delta\mathbf{A} \theta(t)$$

Response to weak incident



Linear Response (Dielectric Function)

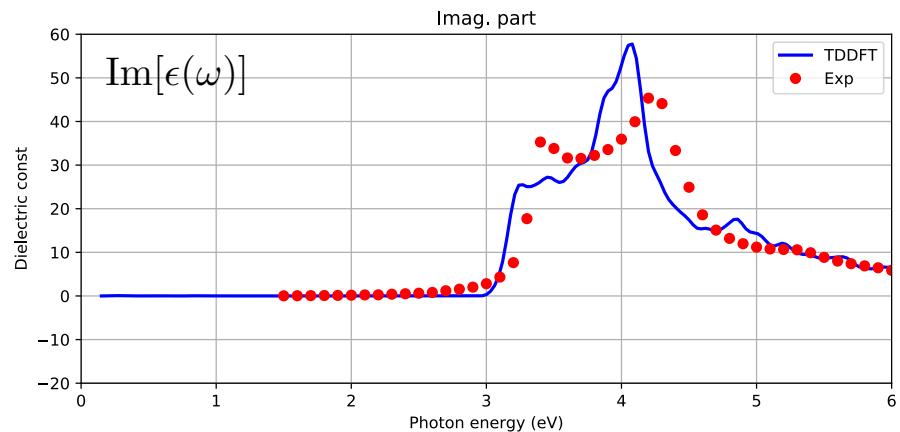
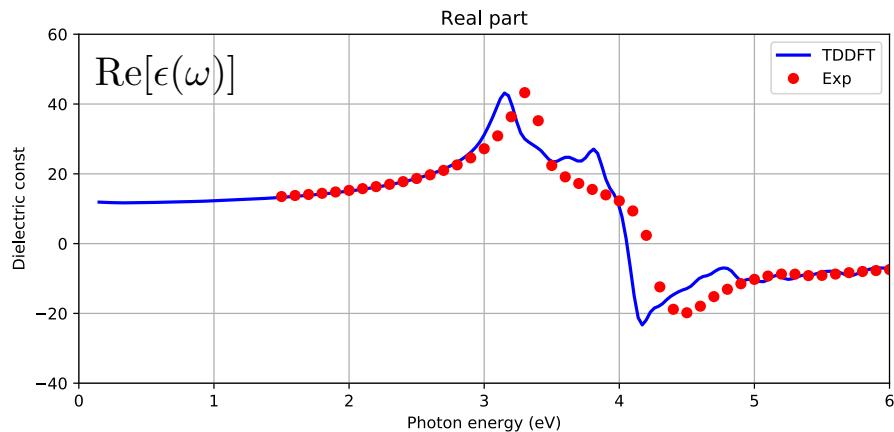
Fourier transformed spectra

Conductivity

$$\sigma(\omega) = \frac{\int J(t)e^{i\omega t} dt}{\int E(t)e^{i\omega t} dt} \quad \leftarrow \quad E_0 \int \delta(t)e^{-i\omega t} dt$$

Dielectric Const.

$$\epsilon(\omega) = \frac{4\pi i}{\omega} \sigma(\omega)$$



(Experimental value from D. E. Aspnes et al. Phys. Rev. B, **27**, 2 (1983))

PART 3

Pulse Response Calculation

Pulse Response Calculation

Solve Time-dependent Kohn-Sham Equation

$$i\hbar \frac{\partial}{\partial t} u_{b,\mathbf{k}}(\mathbf{r}, t) = \left[\frac{1}{2m} \left(-i\hbar\nabla + \hbar\mathbf{k} + \frac{e}{c}\mathbf{A}(t) \right)^2 + v_{\text{ion}} + v_{\text{H}} + v_{\text{XC}} \right] u_{b,\mathbf{k}}(\mathbf{r}, t)$$

...with Strong Incident Pulse $\mathbf{A}(t)$

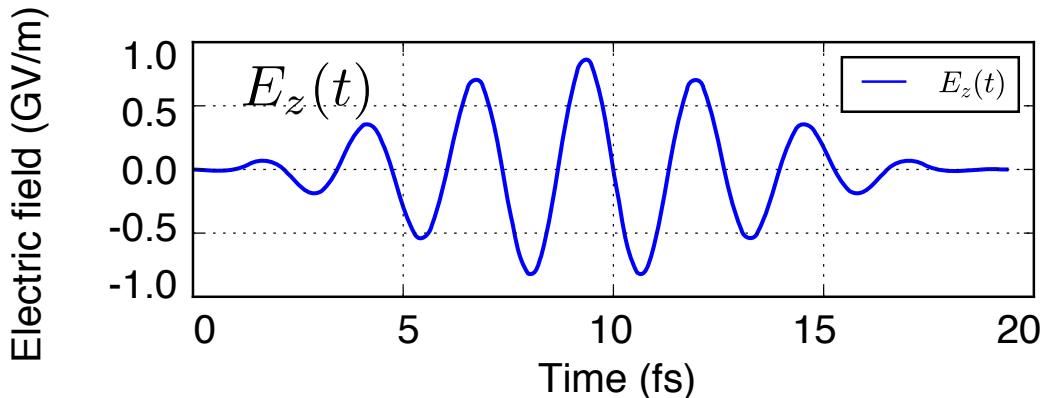


- **Induced Current, Polarization** $\mathbf{J}(t), \mathbf{P}(t) = \int \mathbf{J}(t) dt$
- **Nonlinear optical constants** $\chi^{(2)}, \chi^{(3)}, \dots$
- **Excitation Energy** $E_{\text{ex}}(t) = E_{\text{tot}}(t) - E_{\text{tot}}(0)$
- **Projection to Ground State and Number of Excited Electrons:**

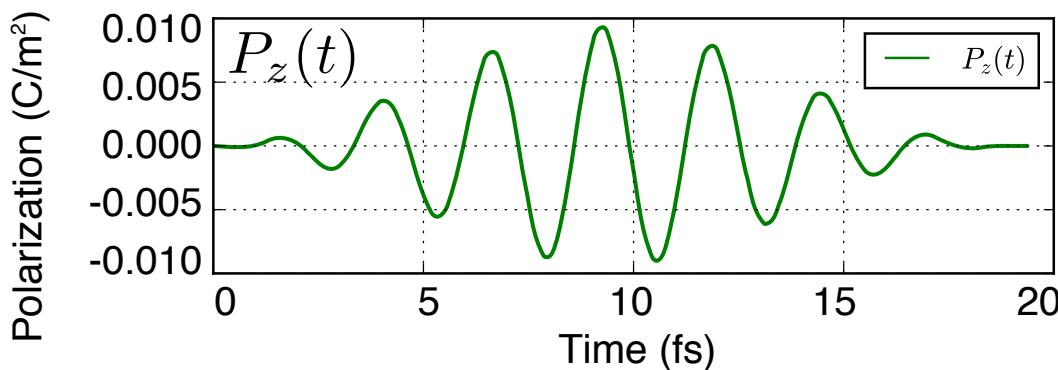
$$n_{\text{ex}} = N_{\text{elec}} - \sum_{\mathbf{k}} \sum_{b,b'}^{\text{(occ)}} |\langle u_{b,\mathbf{k}}^{\text{GS}} | u_{b',\mathbf{k}}(t) \rangle|^2 f_{\mathbf{k}}$$

Nonlinear Responses from SiO₂ Crystal

Applied electric field



Calculated polarization

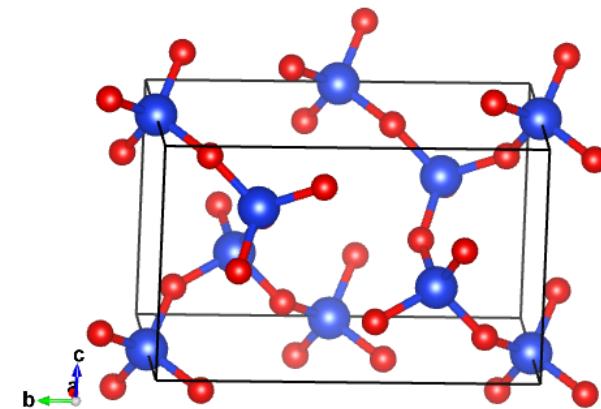


Incident pulse

- Pulse shape function

$$A(t) = A_0 \cos^2 \frac{\pi t}{T} \sin \omega_1 t$$

- Central frequency $\omega_1 = 1.55$ eV
Phase length $T_p = 20$ fs

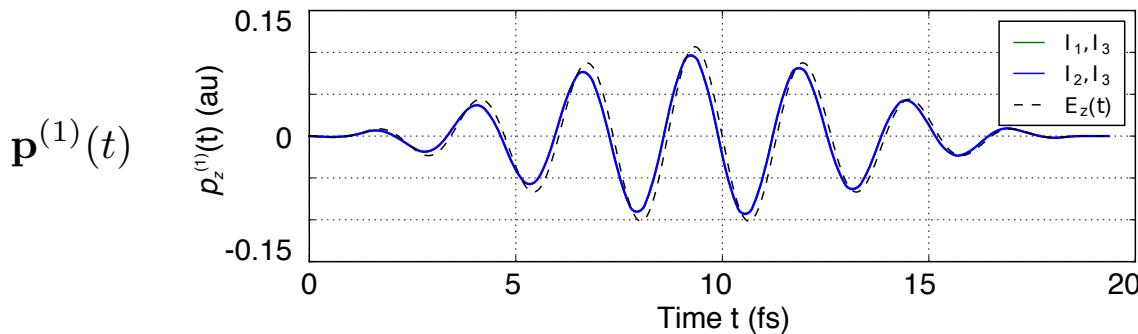


Nonlinear Responses from SiO₂ Crystal

- Numerically expanded the SiO₂ responses to the $\mathbf{p}^{(1)}$ and $\mathbf{p}^{(3)}$ components

$$\mathbf{P}(t) = \mathbf{p}^{(1)}(t)E + \mathbf{p}^{(2)}(t)E^2 + \mathbf{p}^{(3)}(t)E^3 + \dots$$

\uparrow Linear \uparrow Second order \uparrow Third order

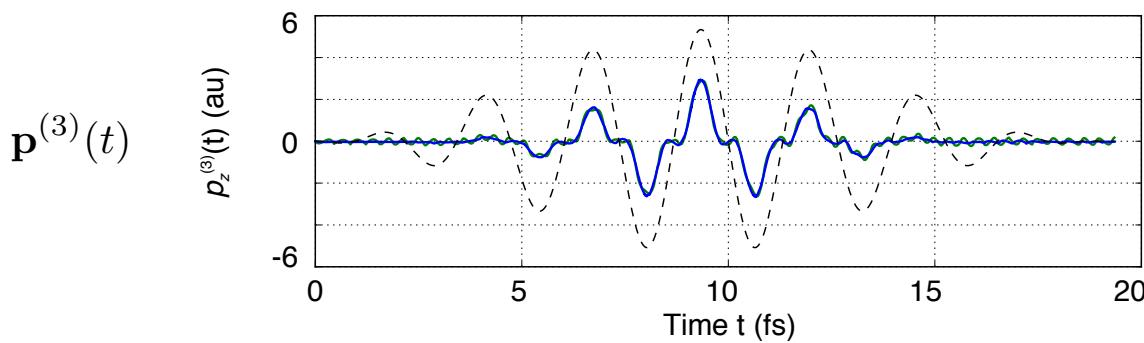


Pulse intensity

$$I_1 = 1 \times 10^{10} \text{ W/cm}^2$$

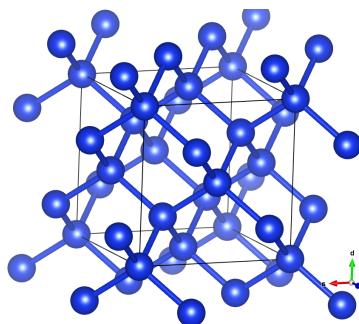
$$I_2 = 5 \times 10^{10} \text{ W/cm}^2$$

$$I_3 = 1 \times 10^{11} \text{ W/cm}^2$$



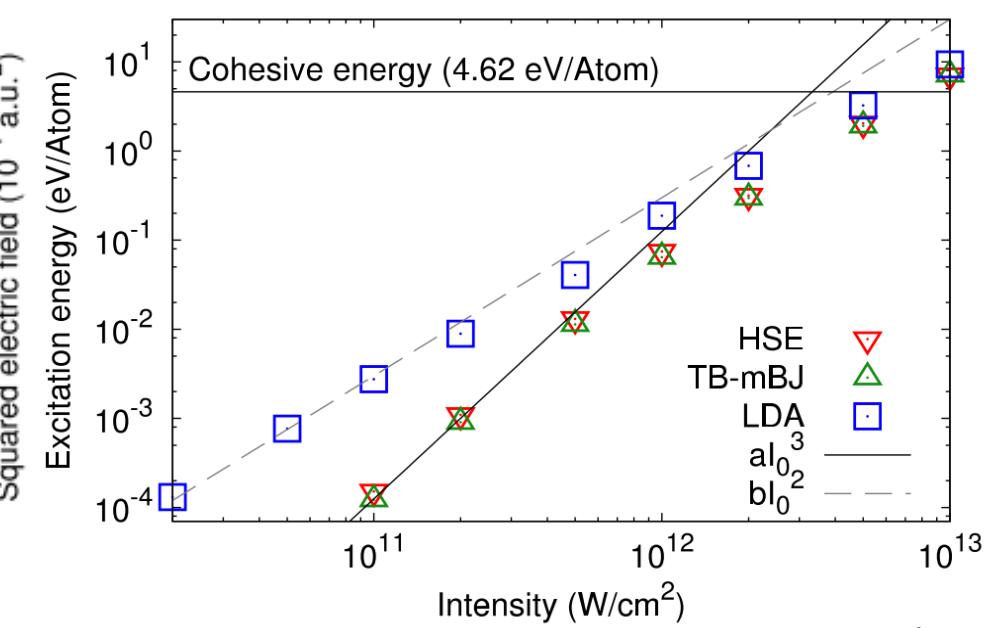
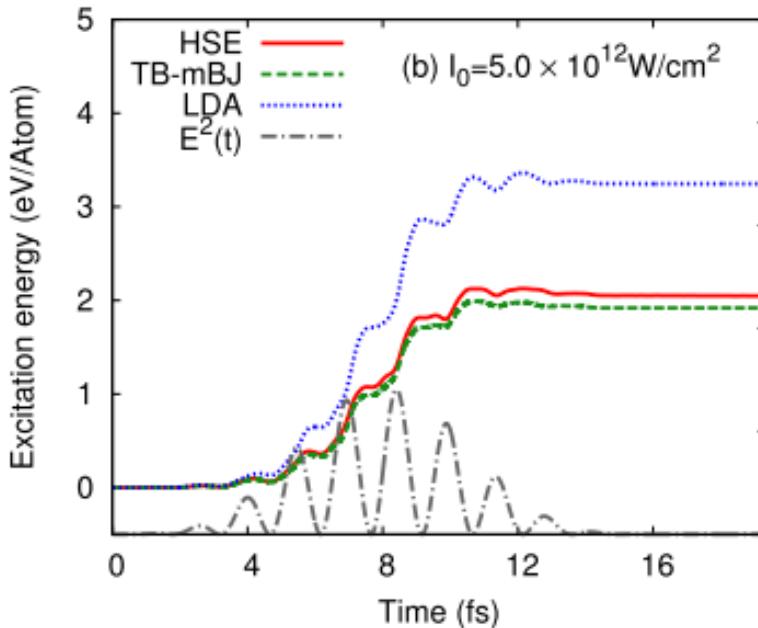
- $\chi^{(3)} = 4.32 \times 10^{-22} \text{ V}^2/\text{m}^2$ (LDA),
- $= 1.34 \times 10^{-22} \text{ V}^2/\text{m}^2$ (mGGA)
- Experiment $\chi^{(3)} = 2.5 \times 10^{-22} \text{ V}^2/\text{m}^2$

Excitation Energy of Silicon Crystal



Excitation energy

$$E_{\text{ex}}(t) = E_{\text{tot}}(t) - E_{\text{tot}}(0) \quad \text{or} \quad \int^t \mathbf{J}(t') \mathbf{E}(t') dt'$$



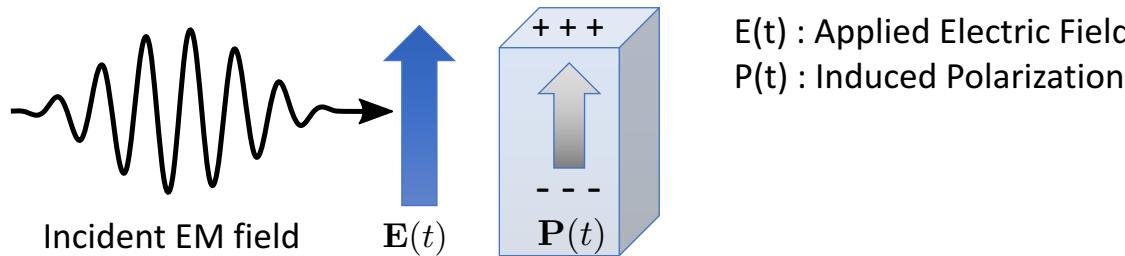
S. A. Sato, K. Yabana et al. J. Chem. Phys. **143**, (2015).

PART 4

Multiscale Maxwell+TDDFT Calculation

Light Propagation in Solid State Material

Consider the light irradiation into the solid material,



Weak intensity light

- Dielectric response to applied field → **Linear Response**

$$\mathbf{P} = \chi^{(1)} \mathbf{E} = (\varepsilon - 1)/4\pi \cdot \mathbf{E}$$

- Light propagation in the solid media → **Maxwell's wave equation.**

$$-\nabla \times \nabla \times \mathbf{A}(\mathbf{r}, t) - \frac{\varepsilon}{c^2} \frac{\partial^2}{\partial t^2} \mathbf{A}(\mathbf{r}, t) = 0$$



Strong intensity light

Light Propagation in Solid State Material

Induced current density in matter

$$\mathbf{J}(t) = -\frac{e}{m} \sum_{b,\mathbf{k}} \frac{1}{\Omega} \int_{\Omega} \operatorname{Re} u_{b,\mathbf{k}}^*(\mathbf{r}, t) \left(-i\hbar\nabla + \hbar\mathbf{k} + \frac{e}{c} \mathbf{A}(t) \right)^2 u_{b,\mathbf{k}}(\mathbf{r}, t) \, d\mathbf{r} + \mathbf{J}_{\text{NL}}$$



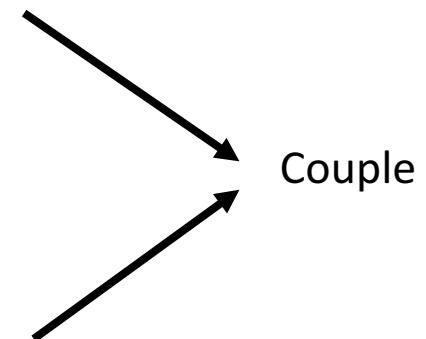
- “**Constitution Relation**” of Electromagnetics:
(Current density can be described as the functional of the EM field)

$$\mathbf{J} = \mathbf{J}[\mathbf{A}(t)]$$

Light propagation in the media

- Governing equation of EM field (Maxwell's wave eq.)

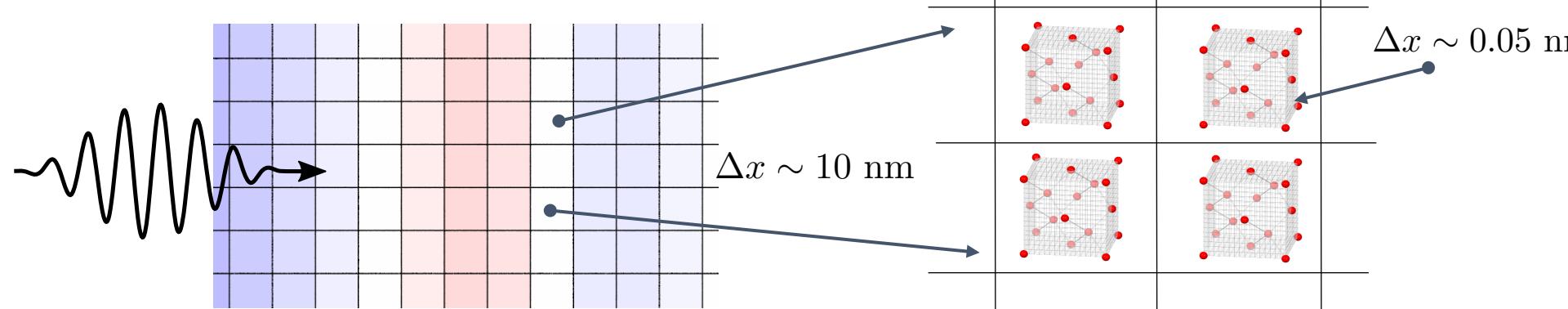
$$-\nabla \times \nabla \times \mathbf{A} - \frac{1}{c^2} \frac{\partial}{\partial t^2} \mathbf{A} = -\frac{4\pi}{c} \mathbf{J}$$



Multiscale Maxwell-TDDFT calculation

Macroscopic system (EM field)

Microscopic system (Electron dynamics)



Solve Maxwell's Eq. in Macroscopic grid:

$$\nabla \times \nabla \times \mathbf{A} + \frac{1}{c^2} \frac{\partial^2 \mathbf{A}}{\partial t^2} = \frac{4\pi}{c} \mathbf{J}$$

FDTD-based EM calculation:

$$\mathbf{J}(t - \Delta t_i) \rightarrow \mathbf{A}(t)$$

Solve TD-KS Eq. in Microscopic Grid

$$\hat{E}u_{n\mathbf{k}} = \hat{\mathcal{H}}(k)u_{n\mathbf{k}}$$

RT-TDDFT calculation:

$$\mathbf{A}(t - \Delta t_i) \rightarrow \mathbf{J}(t)$$

Exchange J and A at every time step

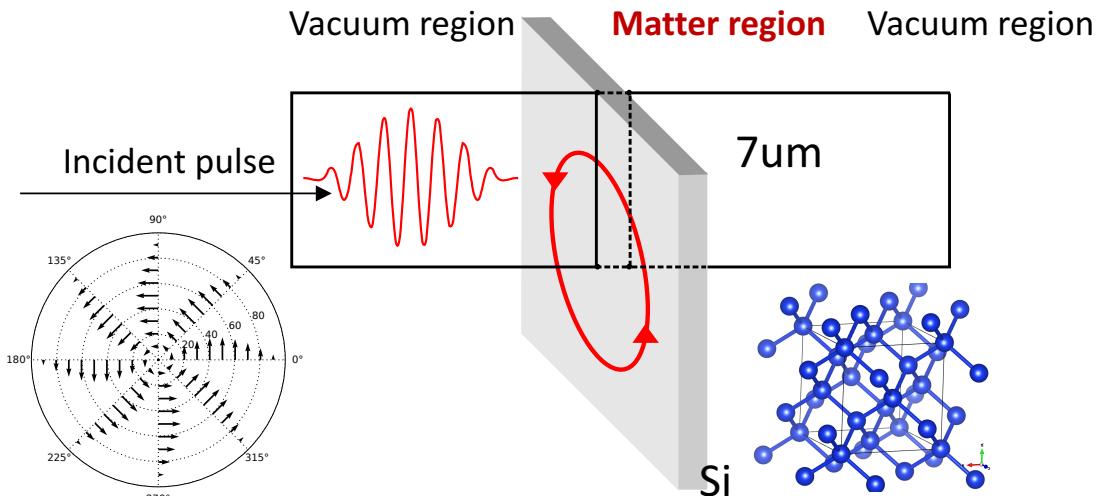
Example of Multiscale Calculation

2 Dimensional problem

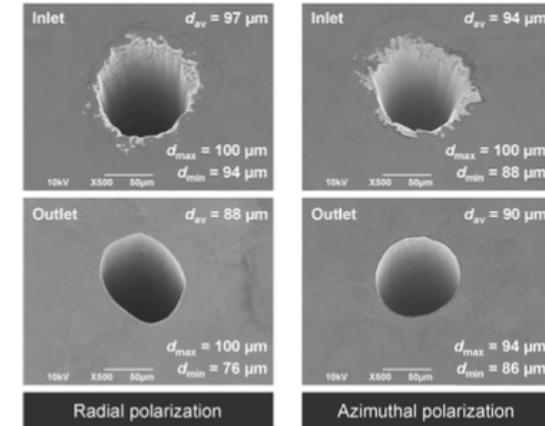
- Cylindrical symmetric case
 - Light propagation to thin film semiconductor
- Application
 - Simulation of Laser Processing by Cylindrical Vector Beam

Computation model

- Consider the laser pulse irradiation to thin-film ($d \sim 7\mu\text{m}$) Silicon crystal



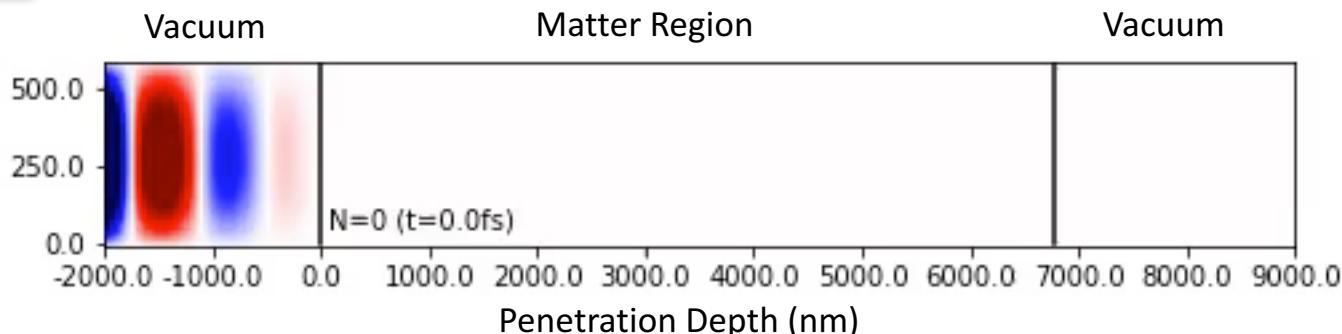
- Incident pulse
 - Frequency: 1.55 eV
 - Pulse length: 16 fs
 - Azimuth polarized beam
 - $I = 10^{12} \text{ W/cm}^2$



Martin Kraus et al, OpEx, 18., 21

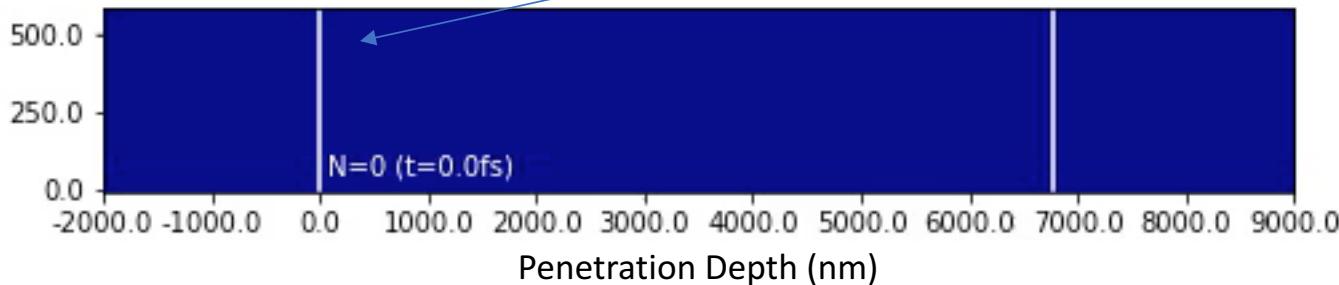
Example of Multiscale Calculation

EM Field



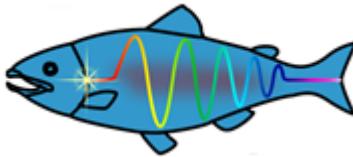
Electronic Excitation Energy

Energy absorption by the multi-photon excitation process



- $512 \times 64 = 32768$ macroscopic points

Conclusion



SALMON

Scalable Ab-initio Light-Matter simulator for Optics and Nanoscience

Isolated System (Molecule)

Periodic System (Solid material)

Ground State Calculation: Total energy, DoS, Charge density profile ...

Linear Response Calculation: Dielectric function, Oscillator strength ...

Pulse Reponse Calculation: Nonlinear excitation, Energy transfer ...

Maxwell+TDDFT Multiscale Calculation

Let's enjoy your research life with SALMON !